

# Early Damage Detection in Power Electronics Using Thermal RC Networks

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# Early Damage Detection in Power Electronics Using Thermal RC Networks

- Motivation
- Development Tasks
- Results and Insights
- Conclusions and further research priorities



# Motivation

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## Importance of Early Damage Detection

- Autonomous systems demand ultra-reliable electronics
- Critical for ensuring reliability and safety in electronic components
- E.g. autonomous driving
  - can only be achieved via redundant systems
  - Redundant systems add weight and high costs of the vehicle
  - Bulky monitoring limits practical on-board integration

## Challenges in Power Electronics

- High currents, thermal loads require efficient dissipation
- Addresses challenges in algorithm performance, power management, and system complexity

## New Technology Approaches and Methods “On-Board Thermal Spectroscopy”

- Thermal spectroscopy and electrothermal models for monitoring, but not detecting, faults in power MOSFETs
- Development of algorithms that leverage thermal impedance curves to identify and classify damage types
- Integration of virtual simulations to replicate damage scenarios

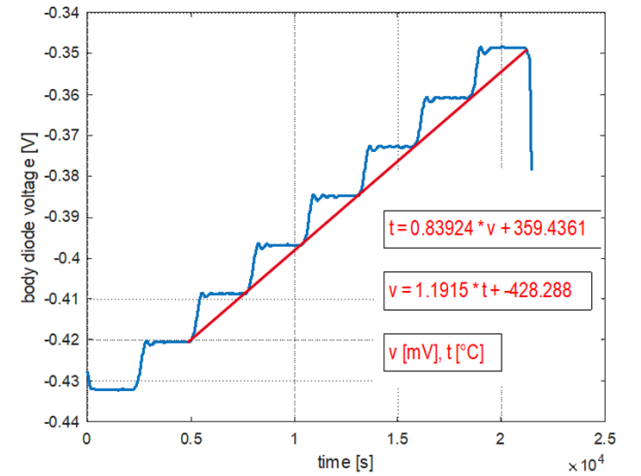
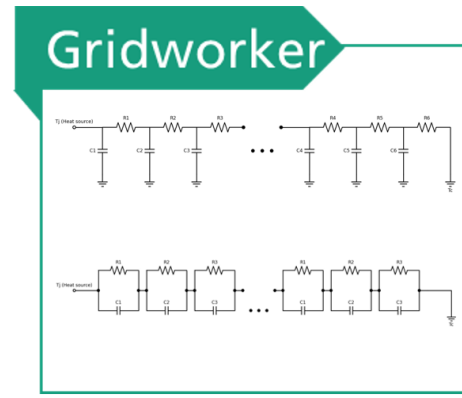
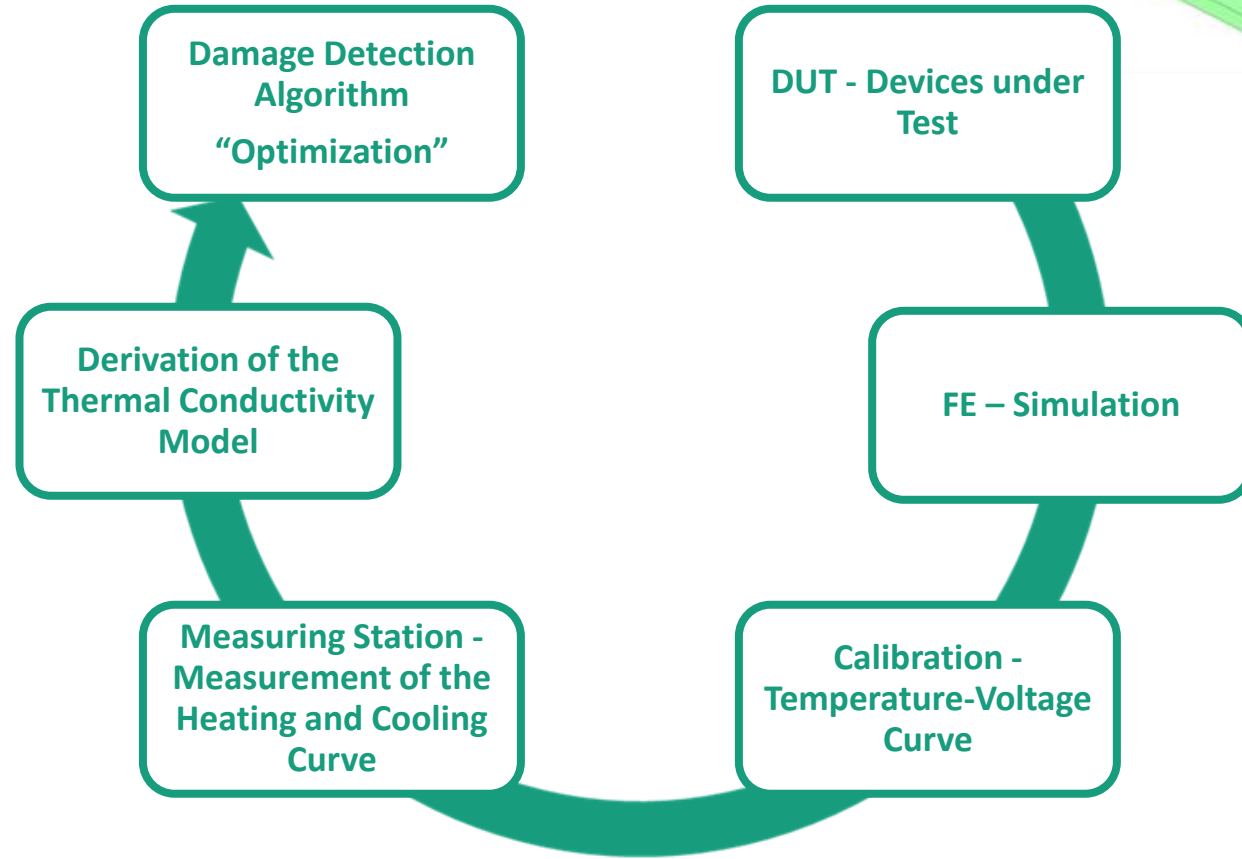
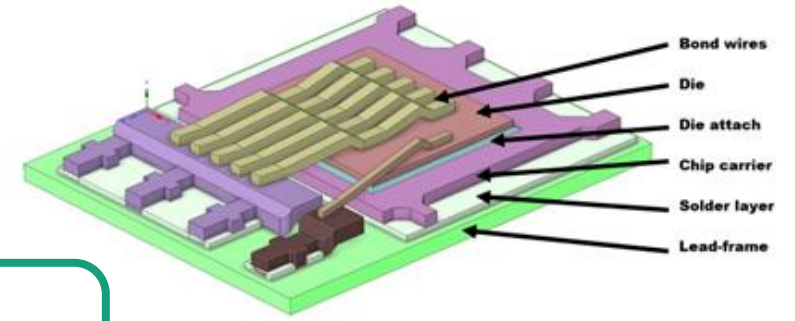
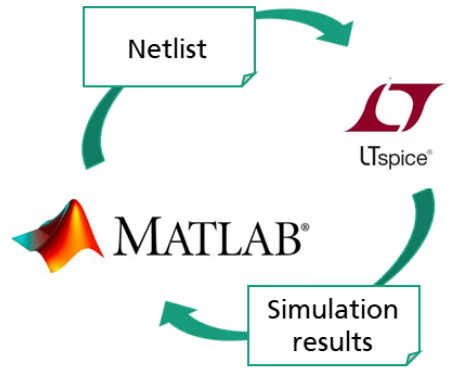
# Early Damage Detection in Power Electronics Using Thermal RC Networks

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- Development Tasks
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# Development Tasks

## Our Approach - Concept



# Development Tasks

## Our Approach - Concept

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### Research objectives

- Development of an early damage detection method based on on-board thermal spectroscopy
- Investigation of different manufacture variants in relation to the derived RC model
- Investigation of ageing effects in the context of early damage detection

### Key challenges

- Derivation and optimization of the thermal resistance model (1D heat transfer) of the system
- Evaluation of different manufacturing variants in relation to the derived RC model



# Development Tasks

## DUT - Devices under Test

**GLD**



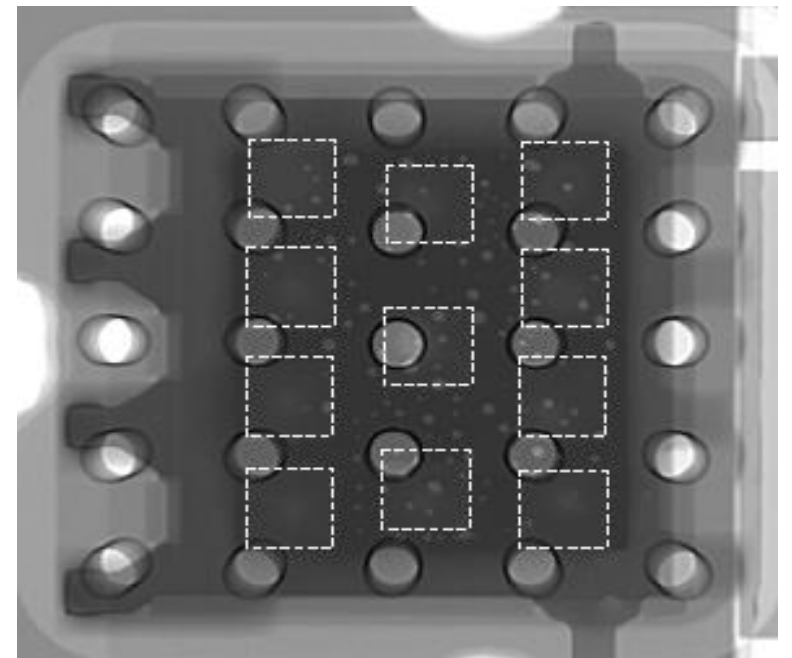
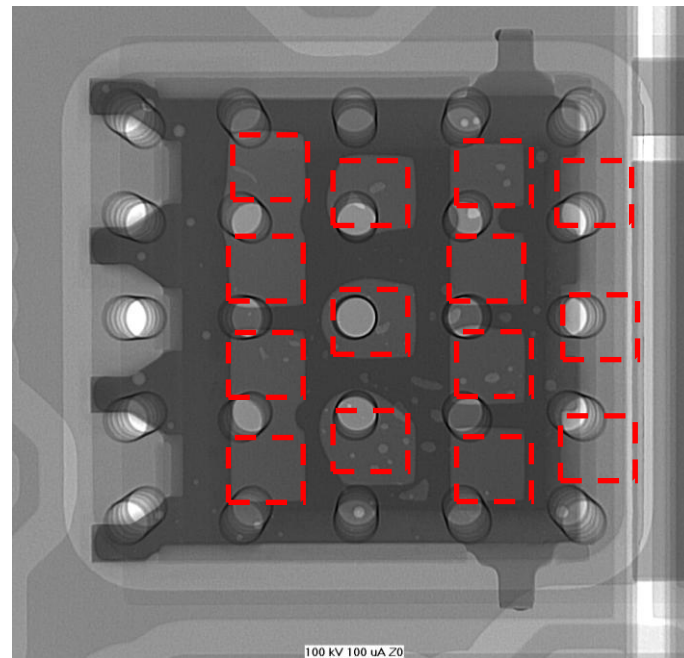
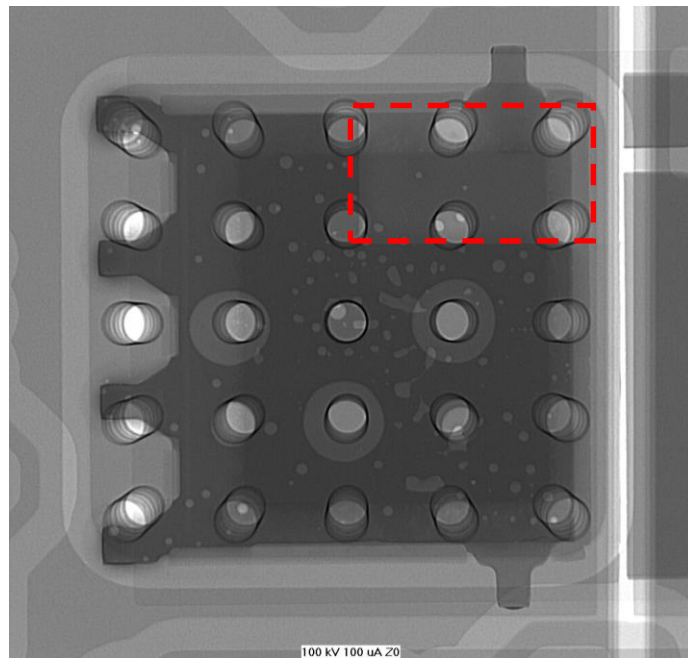
**B30**



**E30**

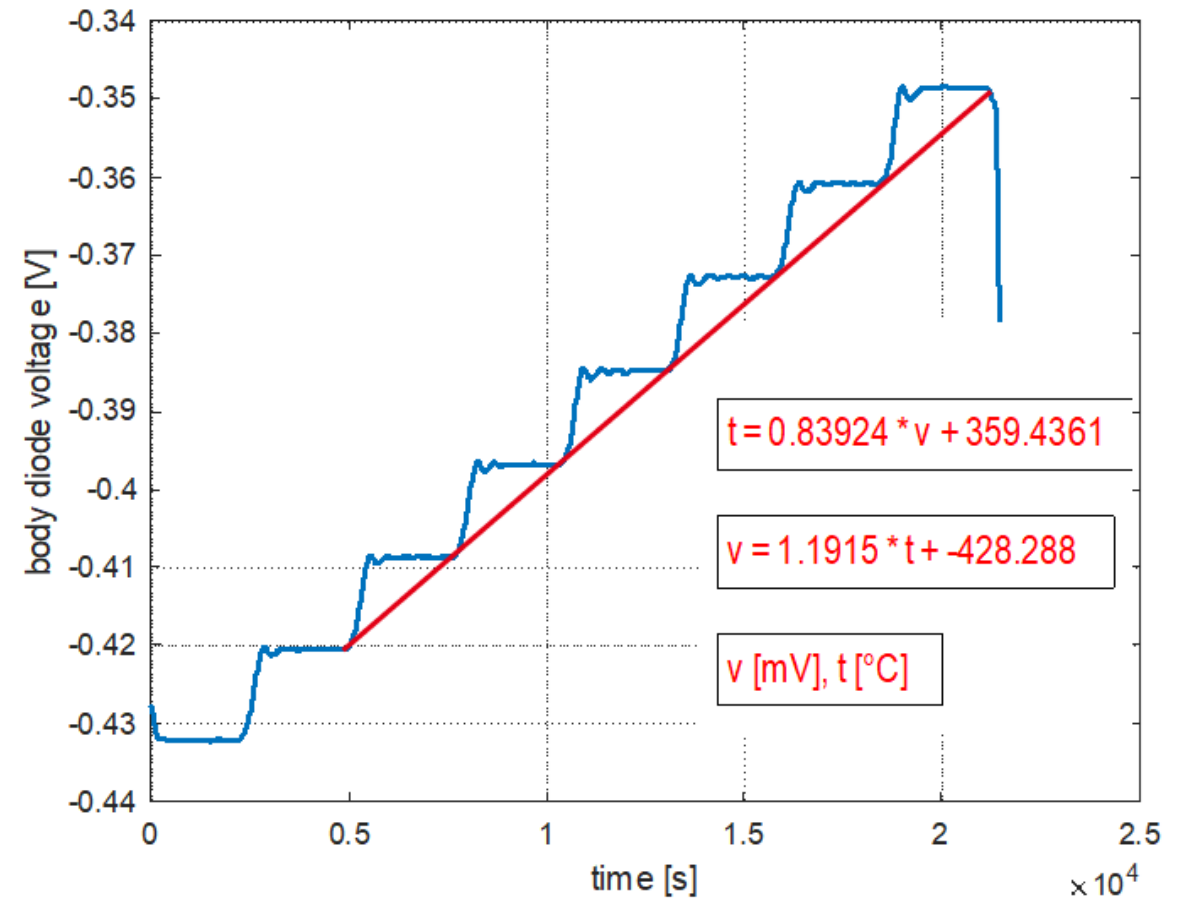


**I40**



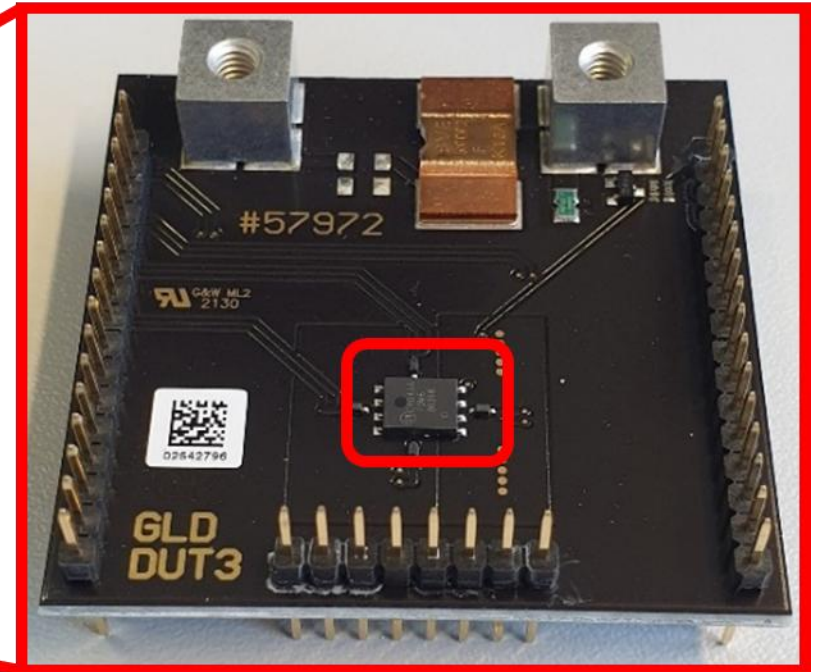
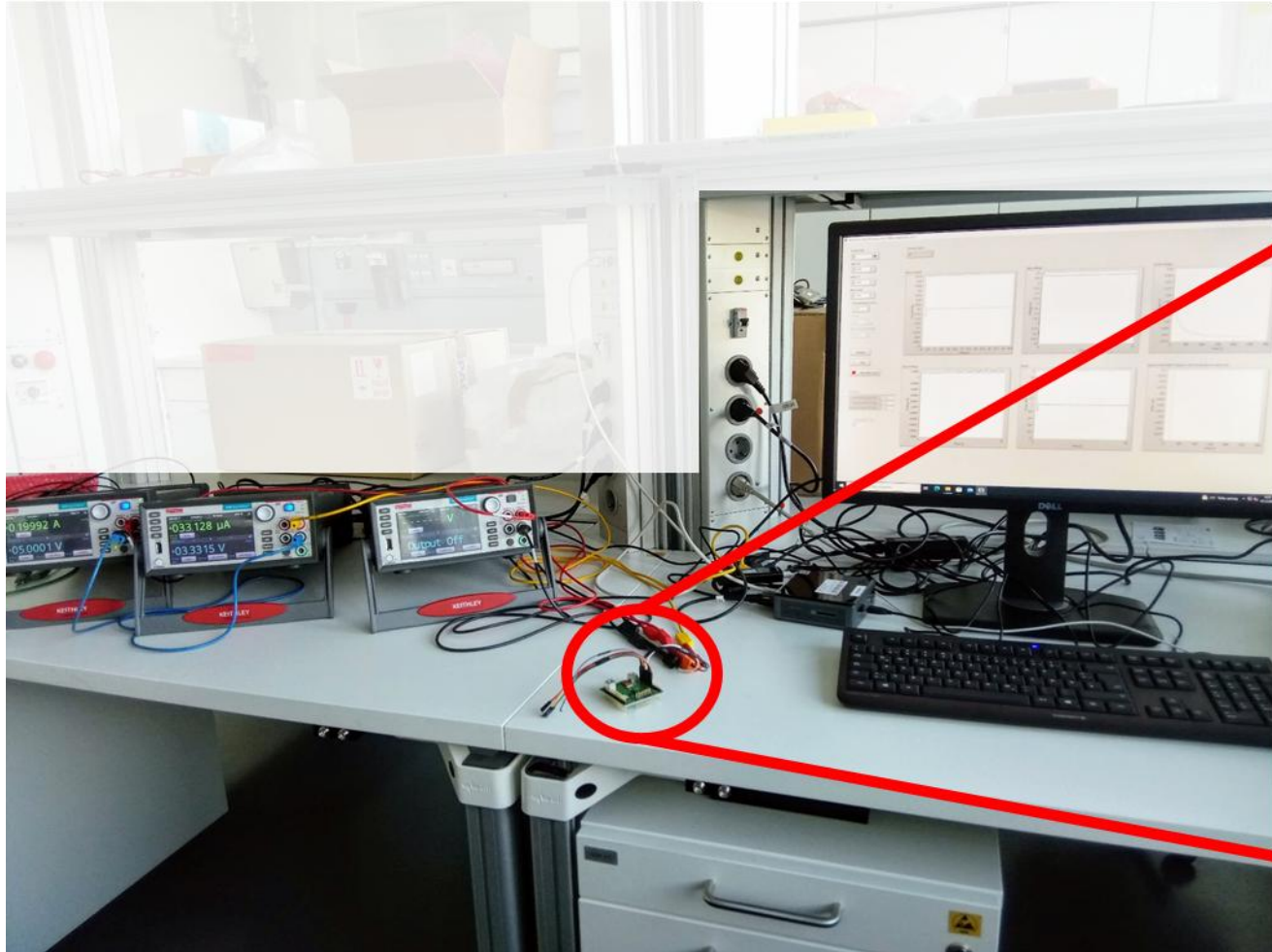
# Development Tasks

## Calibration – Temperature - Voltage Curve



# Development Tasks

## Measuring Station – Heating and Cooling Curve

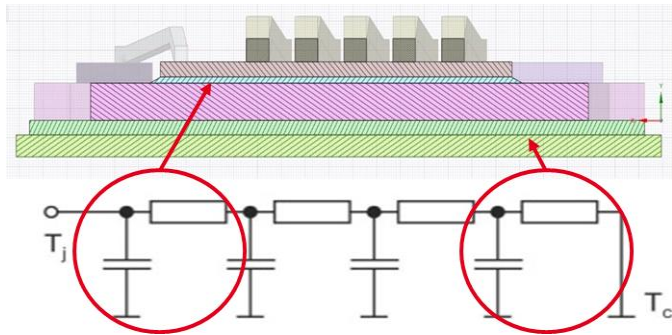


# Development Tasks

## Derivation of the Thermal Conductivity Model

### Physically based mesh

- Derivation or determination of the mesh nodes via the layer geometry and the material properties



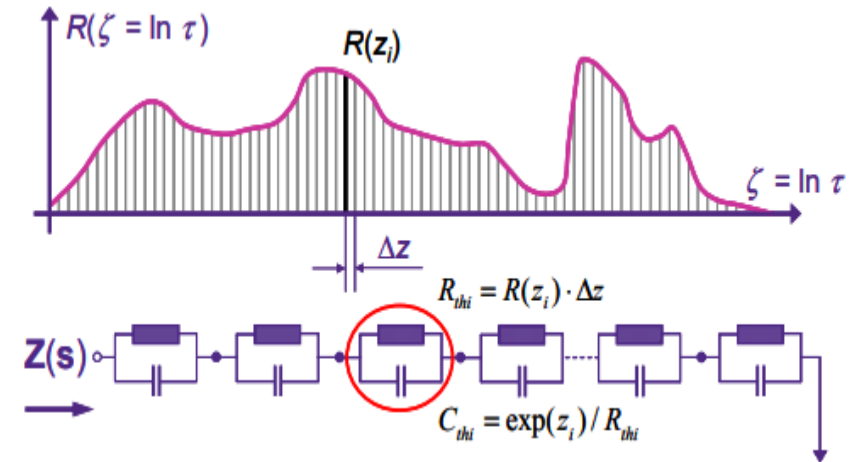
$$R_{th} = \frac{d}{\lambda \cdot A}$$

$$C_{th} = c_p \cdot \rho \cdot A \cdot d$$

$$\tau = R_{th} \cdot C_{th} = \frac{c_p \cdot \rho \cdot d^2}{\lambda}$$

### Mathematically based mesh

- Derivation or determination of the network nodes using the time-constant spectrum “derivation of the impedance function”
- No physical reference => pure optimization challenge

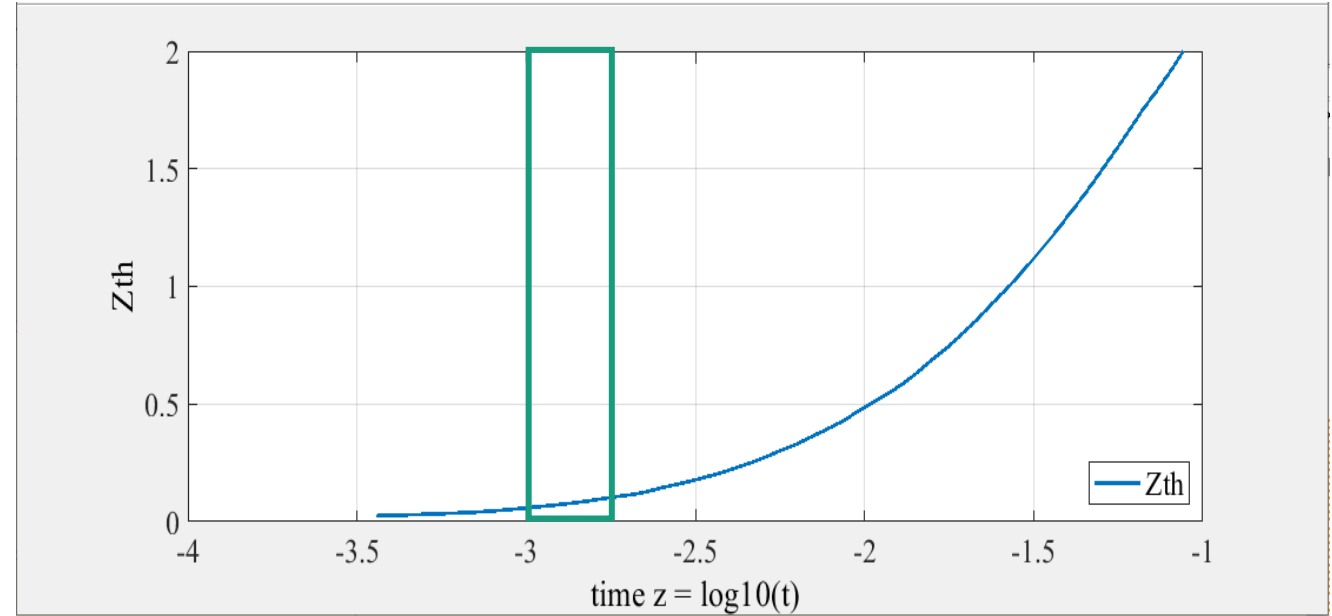


# Development Tasks

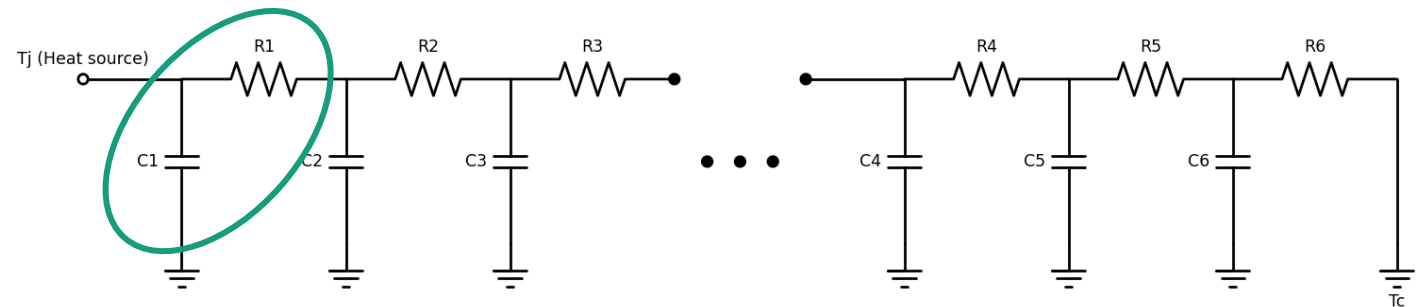
## Derivation of the Thermal Conductivity Model

### Key challenges / milestones

- Determination of the required number of RC nodes
- Definition of the optimization strategy and the restriction conditions
- Determination of the values of the individual RC nodes



$$Z_{th} = \frac{(T_J(t) - T_J(t = 0))}{P_H}$$



# Development Tasks

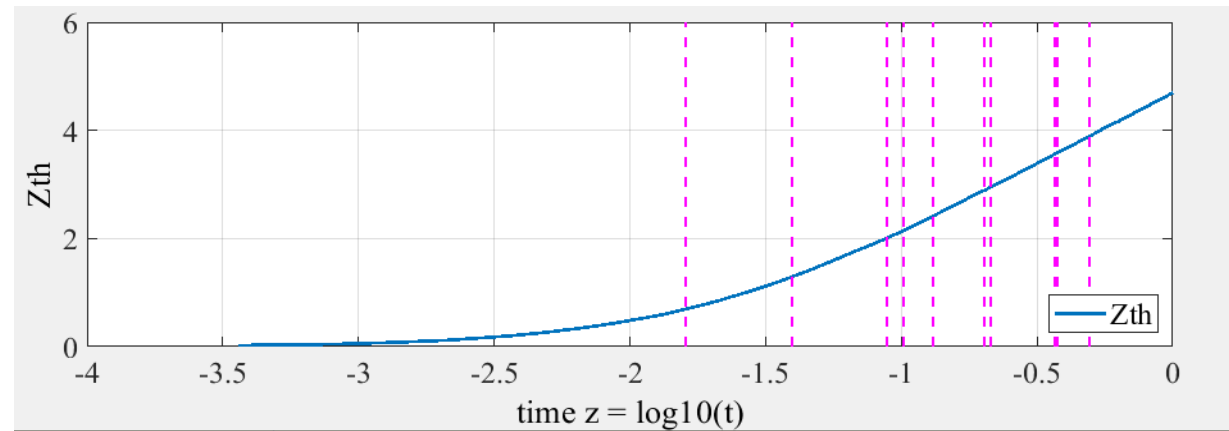
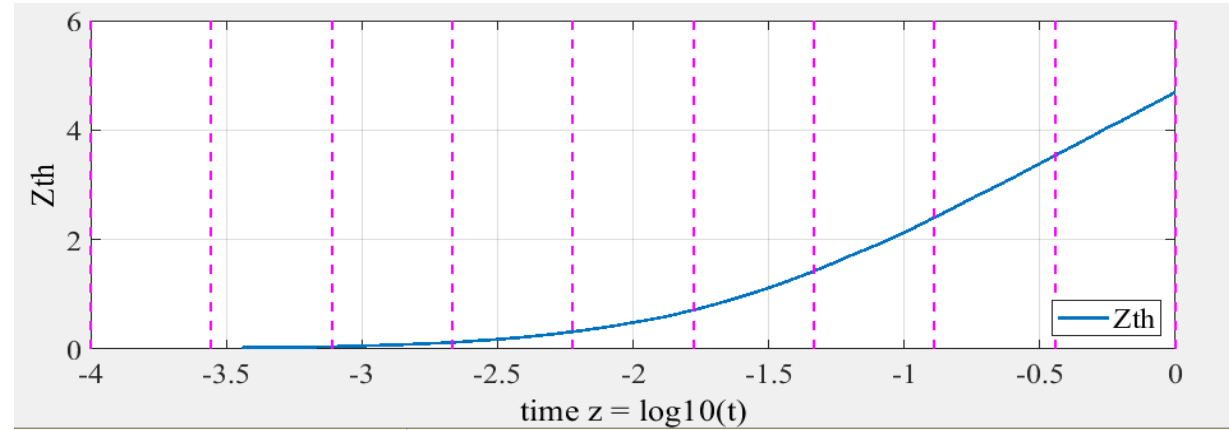
## Derivation of the Thermal Conductivity Model

### Optimization procedures

- FSQP - Feasible Sequential Quadratic Programming
- Powell

### Optimization methods

- Uniform distribution
- Optimization within defined limits
- Free distribution of tau's



# Development Tasks

## Derivation of the Thermal Conductivity Model

### Specific analysis

- Manufacturing tolerances result in sample specific configuration

### Model based analysis

- Based on an idealized sample (average of all individual measurements)

DUT	R1	R2	R3	R4	R5	R6	R7	R8	R9	R10
1	0.8167	1.0482	0.8970	0.6444	0.6416	0.5245	0.2690	0.1583	0.5555	0.7346
2	0.8018	1.0992	0.8977	0.6362	0.6699	0.5177	0.2587	0.1628	0.5887	0.7620
3	0.8247	1.1281	0.9329	0.6521	0.6827	0.5264	0.2663	0.1845	0.5378	0.7001
4	0.8013	1.0875	0.9077	0.6277	0.6479	0.5324	0.2514	0.1739	0.5679	0.7473
5	0.8095	1.0979	0.9272	0.6189	0.6787	0.5365	0.2563	0.1626	0.5887	0.7681
6	0.8058	1.0741	0.9049	0.6577	0.6349	0.5032	0.2647	0.1848	0.5224	0.6632
7	0.8482	1.1772	0.9430	0.6501	0.6828	0.5260	0.2652	0.1616	0.5666	0.7579
8	0.8199	1.0709	0.8959	0.6497	0.6479	0.5299	0.2793	0.1433	0.6347	0.8506
9	0.8239	1.2108	0.7989	0.9497	0.4432	0.4168	0.5546	0.0958	0.6799	0.8551
10	0.7994	1.1421	0.8318	0.8384	0.4904	0.4779	0.4998	0.0957	0.7333	0.9383
11	0.8004	1.0834	0.7980	0.8235	0.4712	0.4730	0.4521	0.1066	0.6380	0.8434
12	0.7812	1.1093	0.7957	0.8331	0.4703	0.4359	0.5547	0.0837	0.7706	0.9943
13	0.8422	1.2213	0.8372	0.8703	0.4873	0.4429	0.5267	0.0896	0.7166	0.9154
14	0.8033	1.1226	0.8592	0.7196	0.6003	0.4919	0.4049	0.1047	0.7143	0.9097
15	0.7976	1.1202	0.8958	0.6526	0.6486	0.5247	0.2794	0.1482	0.5682	0.7731
16	0.8569	1.2366	0.8761	0.8337	0.5307	0.4333	0.5278	0.0863	0.9092	1.2419
17	0.8433	1.1389	0.8351	0.8569	0.5005	0.4367	0.5173	0.0959	0.7154	0.9248
18	0.6119	1.2517	0.6112	1.0998	0.3292	0.4246	0.4895	0.0924	0.6864	0.8953
19	0.7821	1.1408	0.7692	0.9033	0.4229	0.4524	0.5758	0.0788	0.7092	1.1195
20	0.8322	1.1606	0.8343	0.8663	0.4673	0.4504	0.5613	0.0750	0.8712	1.3763

R	*1	*2	*3	*4	*5	*6	*7	*8	*9	*10
Z(Tau)	-1.7955	-1.4008	-1.0541	-0.9910	-0.8832	-0.6933	-0.6685	-0.4356	-0.4258	-0.3087
Ø	0.8064	1.1329	0.8525	0.7703	0.5543	0.4833	0.4047	0.1225	0.6692	0.8926
$\sigma^2$	0.0469	0.0556	0.0707	0.1262	0.1005	0.0398	0.1250	0.0371	0.1025	0.1699



# Development Tasks

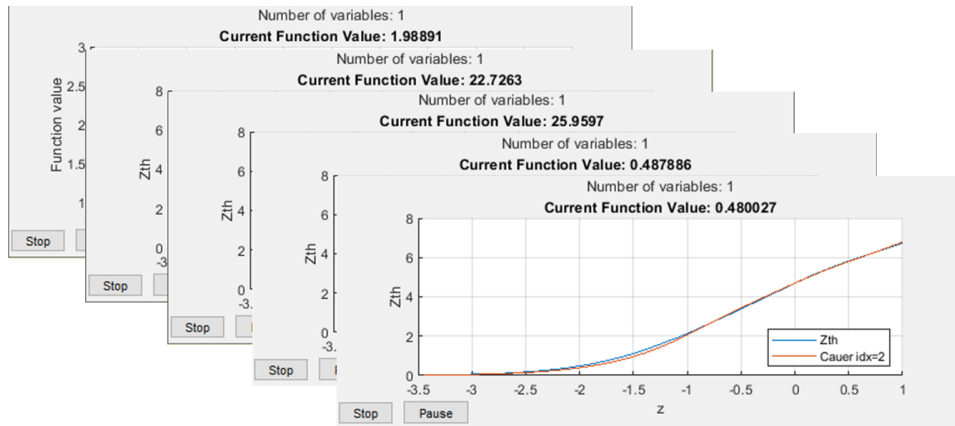
## Damage Detection Algorithm “Optimization”

```

240 |
241 -   objfun = @(Ropt) objectiveFcn (Ropt);
242 |
243 -   for i=1:10
244 -       idx=i;
245 -       Rstart=R(i)/3;
246 -       Rstop=R(i)*4;
247 |
248 -       options = optimset('Display','iter','TolX',1e-4, 'PlotFcns', ...
249 -           {'optimplotx','optimplotfval'});
250 -       [Ropt,f]=fminbnd(objfun,Rstart,Rstop,options);
251 -       myR(i)=Ropt;
252 -       myf(i)=f;
253 -   end
  
```

```

324 -   function f = objectiveFcn (Ropt)
325 -       global z zth tau R idx f
326 -       aktR=R;
327 -       aktR(idx)=Ropt;
328 -       C = tau./aktR;
329 -       gencauer_opt (C, aktR);
330 -       LTSpicecallCauer_opt
331 |
332 -       zth_opt = interp1 (time,v_jt,10.^z);
333 |
334 -       offs = (zth-zth_opt).^2;
335 -       f = sum(offs);
336 |
337 -   end
  
```



```

250 -   [Ropt,f]=fminbnd(objfun,Rstart,Rstop,options);
  
```

Func-count	x	f(x)	Procedure
1	1.96431	1.98891	initial
2	2.94493	22.7263	golden
3	1.35825	25.9597	golden
4	2.17822	0.487886	parabolic
5	2.16677	0.480369	parabolic
6	2.16384	0.480027	parabolic
7	2.16376	0.480027	parabolic
8	2.1638	0.480027	parabolic
9	2.16496	0.480081	golden
10	2.16426	0.480037	golden
11	2.164	0.480029	golden
12	2.1639	0.480028	golden

Optimization terminated:  
 the current x satisfies the termination criteria using OPTIONS.TolX of 1.000000e-04



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# Results and Insights

## FE - Simulation

- FE model allows simulation of thermal system behaviour for different damages

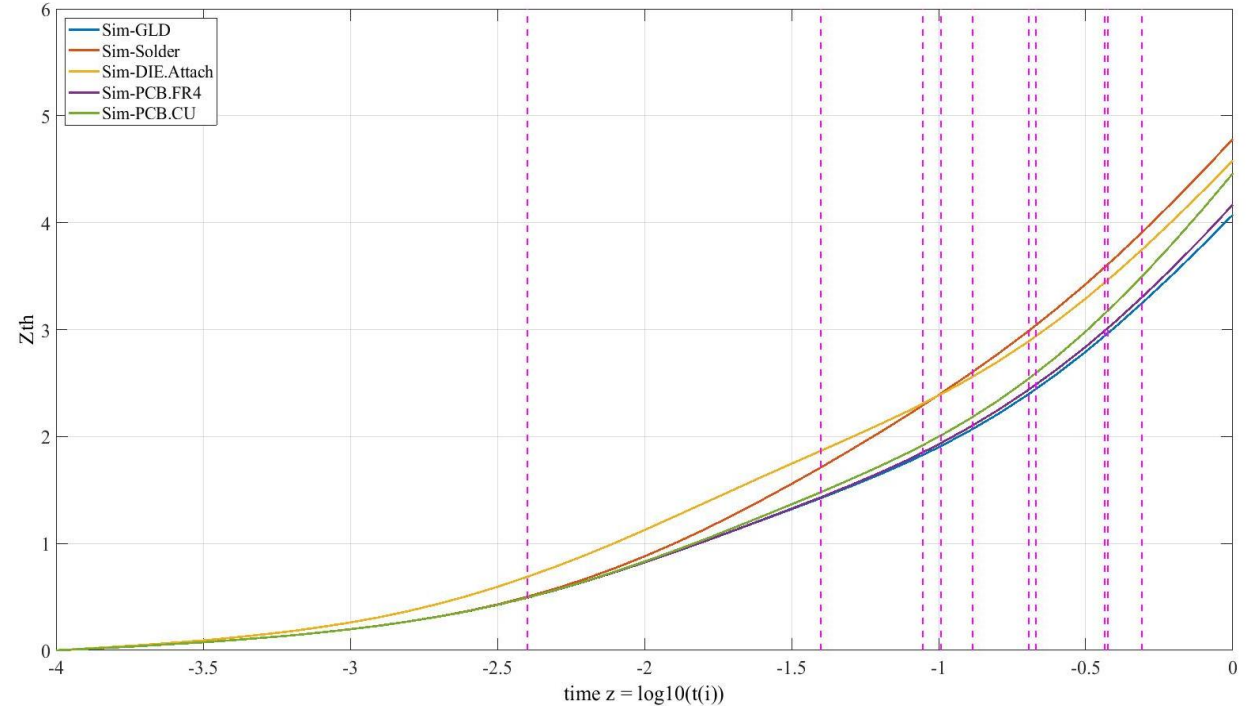
### Specific time deviation

- Die attach - Network element 1
- Solder - Network element 2
- PCB.CU - Network element 4
- PCB.FR4 - Network element 5



### Interpretation of the results

Investigation of ageing effects in the solder => change of the curve Sim-GLD to Sim-Solder



	F(R1)	F(R2)	F(R3)	F(R4)	F(R5)	F(R6)	F(R7)	F(R8)	F(R9)	F(R10)
B30	5.1608	0.3508	2.0542	5.7488	8.7950	12.4074	13.8380	17.4637	20.2662	20.7935
A20DA	0.4731	1.8692	4.8533	7.2362	8.9040	10.7621	11.4483	12.5958	14.0917	14.4117
PCB-FR4	1.2967	0.9235	0.4931	0.1965	0.1712	0.2575	0.3516	0.5213	1.2037	1.4122
PCB-CU	5.8050	3.1911	1.0893	0.2710	0.7567	2.2374	3.1047	6.4467	9.2951	9.8471

# Results and Insights

## Investigation and Evaluation of Various Causes of Faults in the Solder

### The starting point

- Idealised RC mesh

**B30**



	F(R1)	F(R2)	F(R3)	F(R4)	F(R5)	F(R6)
.*744	0.0206	0.0214	0.0199	0.0197	0.0201	0.0208
.*759	0.1024	0.0281	0.0918	0.1999	0.2989	0.3988
.*804	0.1171	0.0138	0.0634	0.1694	0.2675	0.3659
.*819	0.2545	0.0197	0.0435	0.1720	0.3044	0.4434
.*834	0.5750	0.0446	0.1296	0.4613	0.7949	1.1404

### Routine

- Initial adjustments to the individual samples (measurements of the basic state)

**E30**



Nr	F(R1)	F(R2)	F(R3)	F(R4)	F(R5)	F(R6)
.*741	0.0283	0.0100	0.0088	0.0130	0.0182	0.0234
.*756	0.0048	0.0310	0.0489	0.0639	0.0736	0.0827
.*801	0.0447	0.0188	0.0127	0.0150	0.0205	0.0264
.*816	0.0167	0.0370	0.0854	0.1491	0.1972	0.2402
.*831	0.0658	0.0158	0.0227	0.0599	0.0996	0.1419

### Interpretation of the results

- Differentiation between the failure variants could only be proven to a limited extent

**I40**



Nr	F(R1)	F(R2)	F(R3)	F(R4)	F(R5)	F(R6)
.*743	0.0167	0.0052	0.0147	0.0290	0.0399	0.0487
.*758	0.0073	0.0149	0.0188	0.0211	0.0227	0.0241
.*803	0.0103	0.0135	0.0289	0.0476	0.0636	0.0796
.*818	0.0793	0.0214	0.0866	0.1901	0.2811	0.3707
.*833	0.2099	0.0461	0.1813	0.4201	0.6340	0.8457

# Results and Insights

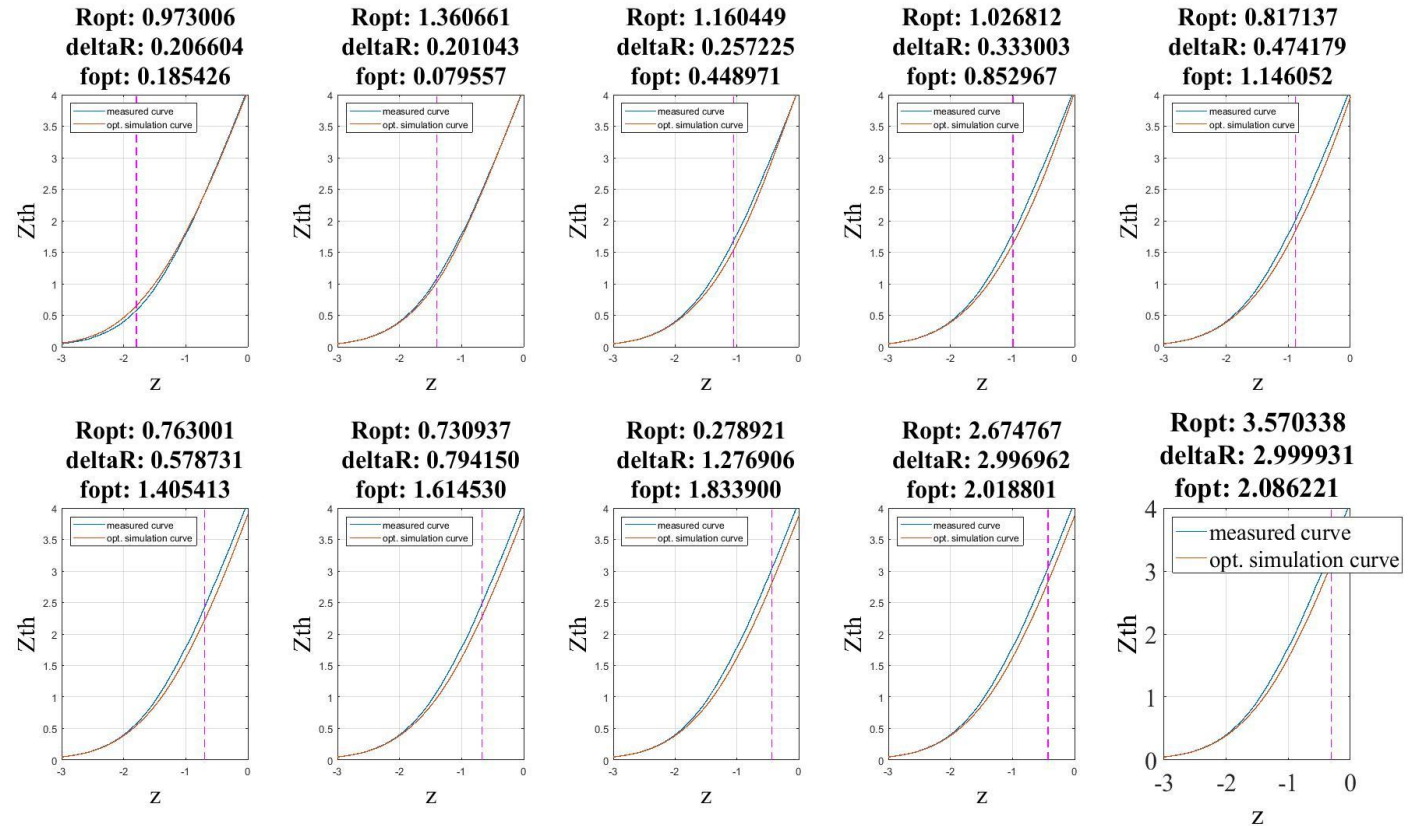
## Evaluation of the Ageing Measurements

### The starting point

- Idealised RC mesh

### Routine

- Initial adjustments to the individual samples (measurements of the basic state)
- Iterative resistance variation 'optimisation' incl. the associated deviation error
- Determination of limits % change in resistance
- Determination of limits of the fault tolerance 'fopt'

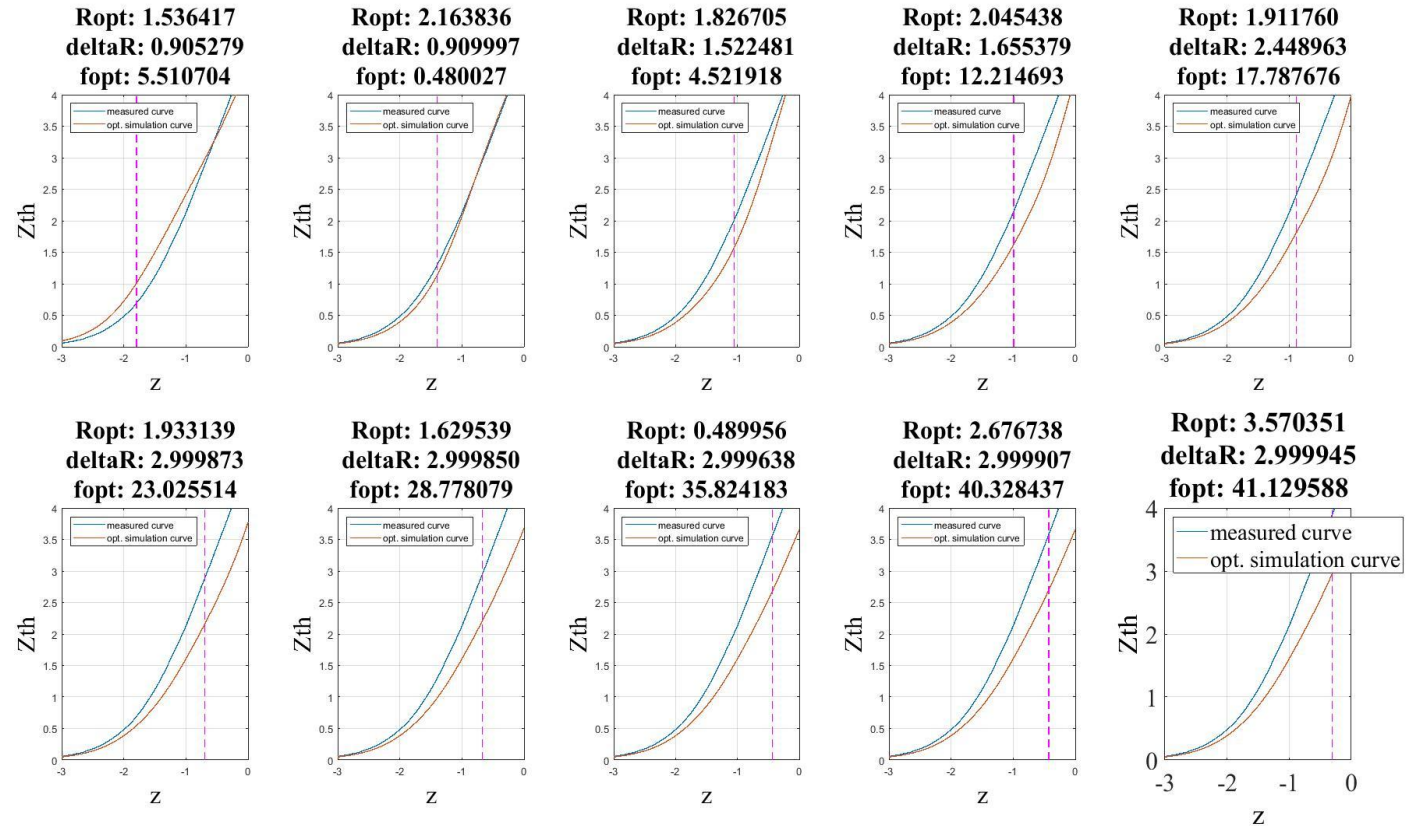


# Results and Insights

## Evaluation of the Ageing Measurements

### Interpretation of the results

- Ageing effects lead to significant changes in the coefficient values (1.133  $\Omega$  -> 2.164  $\Omega$ )
- Reliable assessment based on the ‘fopt’ quality criterion
- Decision criteria such as a percentage change of R could further improve clarity



# Results and Insights

## Evaluation of the Ageing Measurements

	F(R1)	F(R2)	F(R3)	F(R4)	F(R5)	F(R6)	F(R7)	F(R8)	F(R9)	F(R10)
.*700	3.3144	1.5123	2.7242	8.5850	9.5289	13.0708	17.3180	20.5412	22.1616	22.7546
.*702	0.3110	0.1285	0.1495	0.2665	0.4182	0.6340	0.8686	1.1313	1.3674	1.4433
.*716	0.5303	0.1002	0.8796	1.9571	2.7920	3.3624	3.9605	4.5563	4.8788	4.9860
.*731	0.2604	0.0346	0.3279	0.7672	1.1389	1.3618	1.6267	1.8082	1.9140	1.9627
.*747	0.1695	0.0601	0.0410	0.0741	0.1336	0.2180	0.3181	0.3804	0.4975	0.5396
.*761	5.1858	0.5936	5.4936	13.3250	20.1104	25.5624	34.2510	38.9909	40.6542	41.2345
.*791	0.4257	0.1429	0.1327	0.2807	0.4837	0.7626	1.0674	1.4260	1.7218	1.8126
.*796	0.0987	0.0427	0.2010	0.3968	0.5309	0.6154	0.6936	0.7387	0.7659	0.7766
.*822	0.0955	0.0734	0.0889	0.1229	0.1732	0.2339	0.3192	0.3597	0.4465	0.4846
.*841	1.0035	0.1963	1.5496	3.3488	4.7957	5.9421	7.0490	8.4507	9.1310	9.3726



# Early Damage Detection in Power Electronics Using Thermal RC Networks



# Conclusions and further Research Priorities

## ■ The investigations show

- The measurement of the voltage of the body diode can be used to determine the thermal impedance curve of the component
- The evaluation was carried out using validated finite element models and on test boards with various integrated defect patterns
- Test measurements proved that the developed method recognises changes to the package and responds selectively

## ■ Further work

- Variability in manufacturing and measurement inaccuracies can obscure damage detection
- Testing the methods and the algorithm on real ageing methods or in field tests
- Investigation and derivation of threshold values - anomalies, deviations and malfunctions





# Thank You for Your Attention

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# Contact

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